

PXAE261908NF

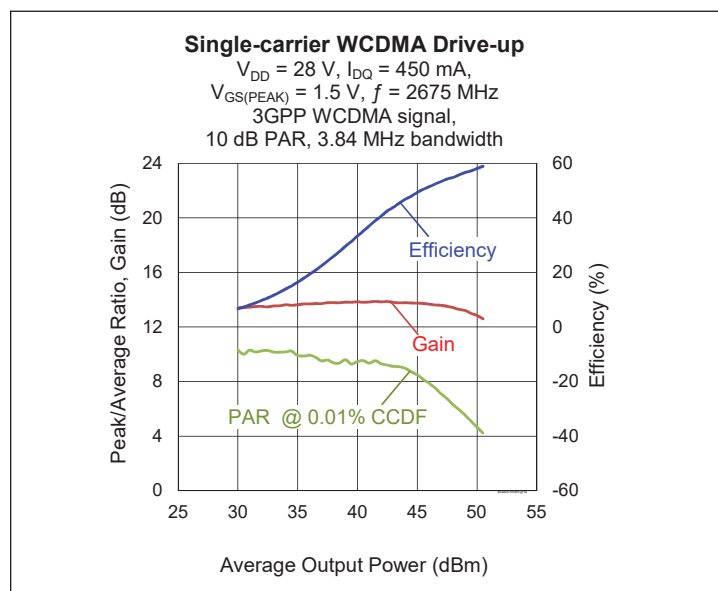
Thermally-Enhanced High Power RF LDMOS FET 240 W, 28 V, 2515 – 2675 MHz

Description

The PXAE261908NF is a 240-watt (P_{3dB}) LDMOS FET intended for use in multi-standard cellular power amplifier applications in the 2515 to 2675 MHz frequency band. Features include input and output matching, high gain and a thermally-enhanced package with earless flange. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PXAE261908NF
Package PG-HBSOF-6-3



Features

- Broadband internal input and output matching
- Asymmetric Doherty design
 - Main: $P_{3dB} = 90\text{ W}$ typical
 - Peak: $P_{3dB} = 180\text{ W}$ typical
- Typical pulsed CW performance, 2675 MHz, 28 V
 - Output power at $P_{1dB} = 51\text{ W}$
 - Output power at $P_{3dB} = 240\text{ W}$
 - Gain = 11.8 dB
 - Efficiency = 60%
- Capable of handling 10:1 VSWR at 28 V, 32 W (CW) output power
- Integrated ESD protection
- Human Body Model, Class 2 (per ANSI/ESDA/JEDEC JS-001)
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Single-carrier WCDMA Specifications (tested in Wolfspeed Doherty test fixture)

$V_{DD} = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $V_{GS(PEAK)} = 1.5\text{ V}$, $P_{OUT} = 32\text{ W}$ avg, $f = 2675\text{ MHz}$, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|----------|------|------|-----|------|
| Gain | G_{ps} | 12.8 | 13.5 | — | dB |
| Drain Efficiency | η_D | 45 | 47.5 | — | % |
| Adjacent Channel Power Ratio | ACPR | — | -28 | -26 | dBc |
| Output PAR at 0.01% probability on CCDF | OPAR | 7.6 | 8 | — | dB |

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



DC Characteristics

| Characteristic | Conditions | Symbol | Min | Typ | Max | Unit |
|--------------------------------|---|---------------|-----|------|-----|---------------|
| Drain-source Breakdown Voltage | $V_{GS} = 0\text{ V}, I_{DS} = 10\text{ mA}$ | $V_{(BR)DSS}$ | 65 | — | — | V |
| Drain Leakage Current | $V_{DS} = 28\text{ V}, V_{GS} = 0\text{ V}$ | I_{DSS} | — | — | 1 | μA |
| | $V_{DS} = 63\text{ V}, V_{GS} = 0\text{ V}$ | I_{DSS} | — | — | 10 | μA |
| Gate Leakage Current | $V_{GS} = 10\text{ V}, V_{DS} = 0\text{ V}$ | I_{GSS} | — | — | 1 | μA |
| On-state Resistance | (main) $V_{GS} = 10\text{ V}, V_{DS} = 0.1\text{ V}$ | $R_{DS(on)}$ | — | 0.08 | — | Ω |
| | (peak) $V_{GS} = 10\text{ V}, V_{DS} = 0.1\text{ V}$ | $R_{DS(on)}$ | — | 0.03 | — | Ω |
| Operating Gate Voltage | (main) $V_{DS} = 28\text{ V}, I_{DQ} = 450\text{ mA}$ | V_{GS} | 2.7 | 3 | 3.3 | V |
| | (peak) $V_{DS} = 28\text{ V}, I_{DQ} = 0\text{ mA}$ | V_{GS} | — | 1.5 | — | V |

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|---------------------------|-----------|-------------|--------------------|
| Drain-source Voltage | V_{DSS} | 65 | V |
| Gate-source Voltage | V_{GS} | -6 to +10 | V |
| Operating Voltage | V_{DD} | 0 to +32 | V |
| Junction Temperature | T_J | 225 | $^{\circ}\text{C}$ |
| Storage Temperature Range | T_{STG} | -65 to +150 | $^{\circ}\text{C}$ |

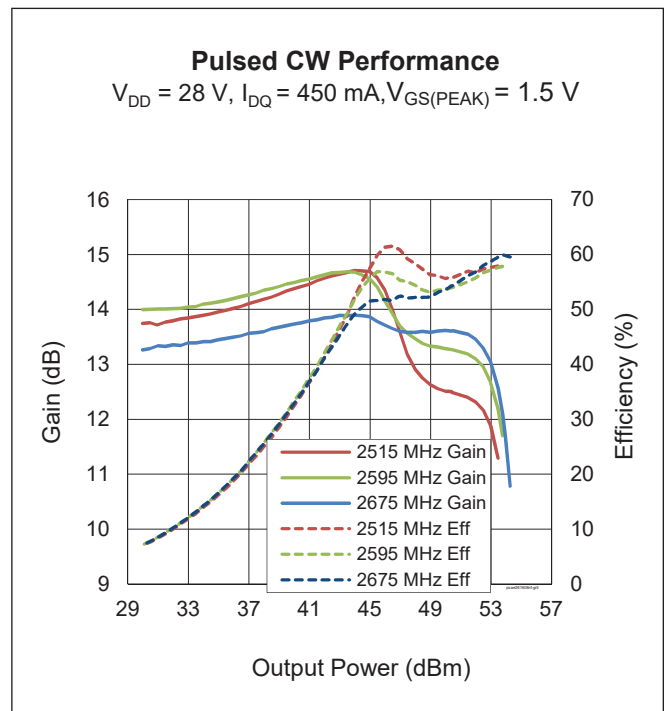
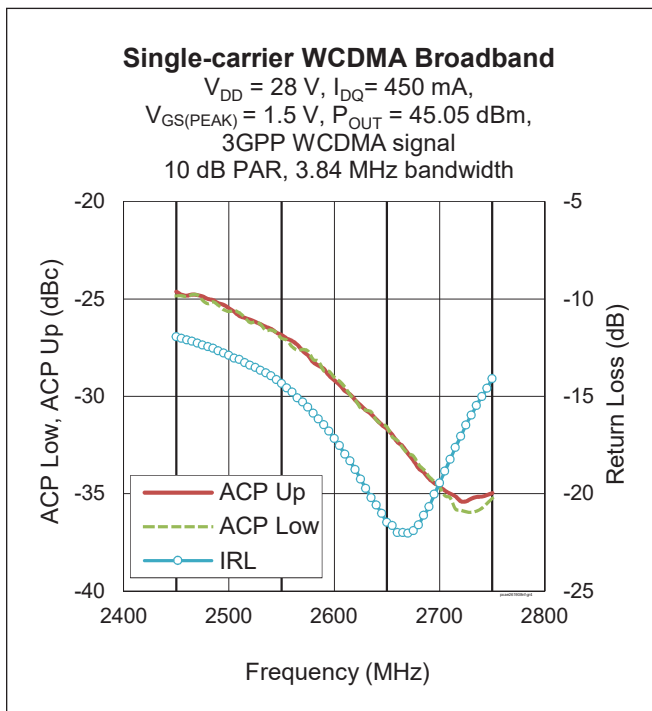
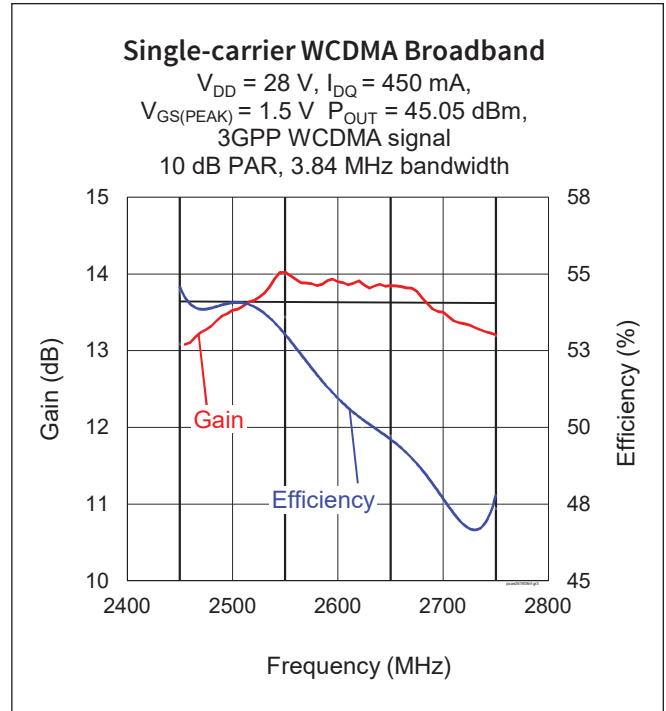
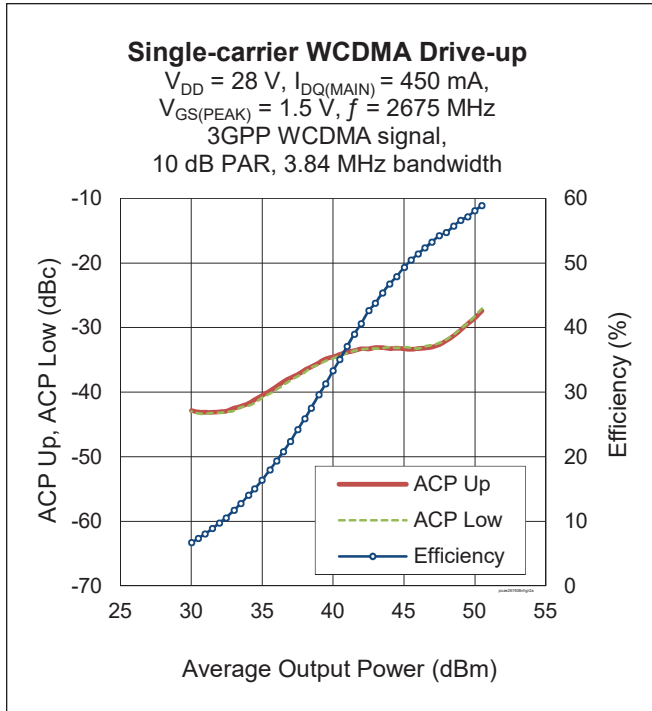
Thermal Characteristics

| Characteristic | Symbol | Value | Unit | |
|--------------------|--|-----------------|------|----------------------|
| Thermal Resistance | (main, $T_{CASE} = 70^{\circ}\text{C}, 32\text{ W CW}$) | $R_{\theta JC}$ | 0.96 | $^{\circ}\text{C/W}$ |
| | (peak, $T_{CASE} = 70^{\circ}\text{C}, 56\text{ W CW}$) | $R_{\theta JC}$ | 0.36 | $^{\circ}\text{C/W}$ |

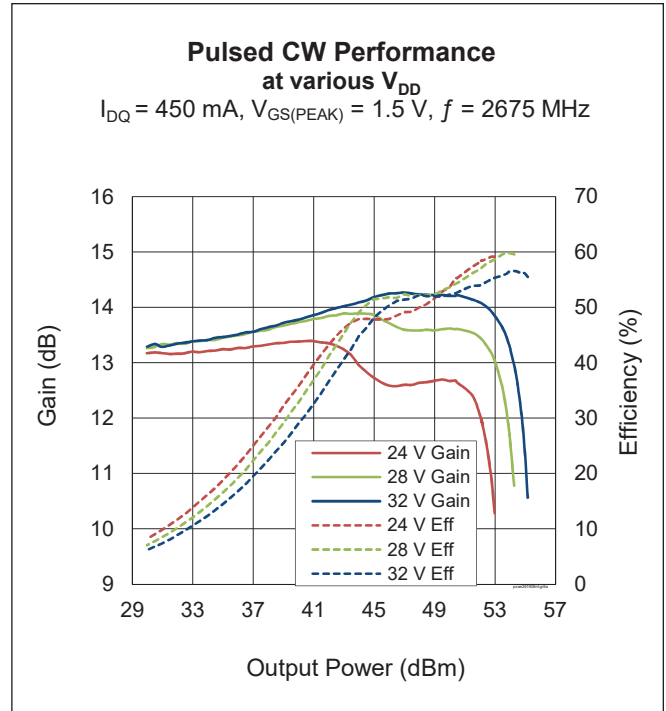
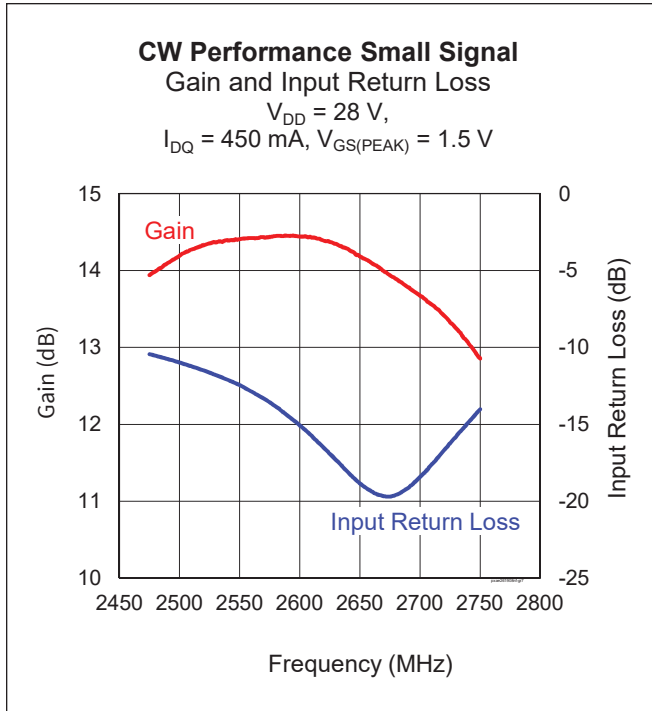
Ordering Information

| Type and Version | Order Code | Package | Shipping |
|--------------------|--------------------|--------------|----------------------|
| PXAE261908NF V1 R5 | PXAE261908NF-V1-R5 | PG-HBSOF-6-3 | Tape & Reel, 500 pcs |

Typical Performance (data taken in a Wolfspeed production test fixture)



Typical Performance (cont.)



Load Pull

Main Side (Doherty) Load Pull Performance – Pulsed CW signal: 10 μsec pulse width, 10% duty cycle, 28 V, IDQ = 460 mA, class AB

| Freq [MHz] | Zs [Ω] | P _{1dB} | | | | | | | | | |
|------------|--------------|------------------|-----------|------------------------|----------------------|--------------------|----------------------|-----------|------------------------|----------------------|--------------------|
| | | Max Output Power | | | | | Max Drain Efficiency | | | | |
| | | Zl [Ω] | Gain [dB] | P _{1dB} [dBm] | P _{3dB} [W] | η _D [%] | Zl [Ω] | Gain [dB] | P _{1dB} [dBm] | P _{3dB} [W] | η _D [%] |
| 2515 | 4.7 - j16.2 | 3.4 - j6.1 | 16.4 | 49.30 | 85 | 55.4 | 5.6 - j4.0 | 18.1 | 48.14 | 65 | 63.0 |
| 2595 | 7.5 - j18.4 | 3.3 - j6.3 | 16.4 | 49.30 | 85 | 54.8 | 5.6 - j4.7 | 18.2 | 48.15 | 65 | 62.0 |
| 2675 | 12.4 - j22.5 | 3.3 - j6.5 | 16.7 | 48.70 | 74 | 49.3 | 5.5 - j4.7 | 18.6 | 47.70 | 59 | 56.0 |

| Freq [MHz] | Zs [Ω] | P _{3dB} | | | | | | | | | |
|------------|--------------|------------------|-----------|------------------------|----------------------|--------------------|----------------------|-----------|------------------------|----------------------|--------------------|
| | | Max Output Power | | | | | Max Drain Efficiency | | | | |
| | | Zl [Ω] | Gain [dB] | P _{3dB} [dBm] | P _{3dB} [W] | η _D [%] | Zl [Ω] | Gain [dB] | P _{3dB} [dBm] | P _{3dB} [W] | η _D [%] |
| 2515 | 4.7 - j16.2 | 3.3 - j6.4 | 14.2 | 50.04 | 101 | 55.3 | 5.7 - j4.1 | 16.1 | 48.80 | 76 | 63.0 |
| 2595 | 7.5 - j18.4 | 3.0 - j6.8 | 14.0 | 50.11 | 103 | 54.0 | 5.4 - j4.8 | 16.1 | 48.90 | 78 | 62.0 |
| 2675 | 12.4 - j22.5 | 3.3 - j7.1 | 14.4 | 49.60 | 91 | 49.3 | 5.4 - j4.2 | 16.7 | 48.30 | 68 | 56.0 |

Tables continued next page



Load Pull (cont.)

Peak Side Doherty Load Pull Performance – Pulsed CW signal: 10 μsec pulse width, 10% duty cycle, $V_{DD} = 28\text{ V}$, $I_{DQ} = 10\text{ mA}$, class B

| | | P_{1dB} | | | | | | | | | | |
|-------------------|--------------------------|--------------------------|------------------|------------------------------|----------------------------|--------------------------|-----------------------------|------------------|------------------------------|----------------------------|--------------------------|--|
| | | Max Output Power | | | | | Max Drain Efficiency | | | | | |
| Freq [MHz] | Z_s [Ω] | Z_l [Ω] | Gain [dB] | P_{3dB} [dBm] | P_{1dB} [W] | η_D [%] | Z_l [Ω] | Gain [dB] | P_{1dB} [dBm] | P_{3dB} [W] | η_D [%] | |
| 2515 | 3.0 – j13.2 | 4.4 – j7.1 | 14.2 | 52.50 | 178 | 58.2 | 4.7 – j3.6 | 15.4 | 51.00 | 126 | 66.0 | |
| 2595 | 3.4 – j14.5 | 4.7 – j8.1 | 14.1 | 52.33 | 171 | 53.4 | 4.4 – j4.1 | 15.7 | 50.90 | 123 | 64.0 | |
| 2675 | 6.3 – j15.0 | 5.8 – j8.7 | 14.4 | 52.20 | 166 | 52.7 | 4.7 – j5.0 | 15.8 | 51.00 | 126 | 60.0 | |

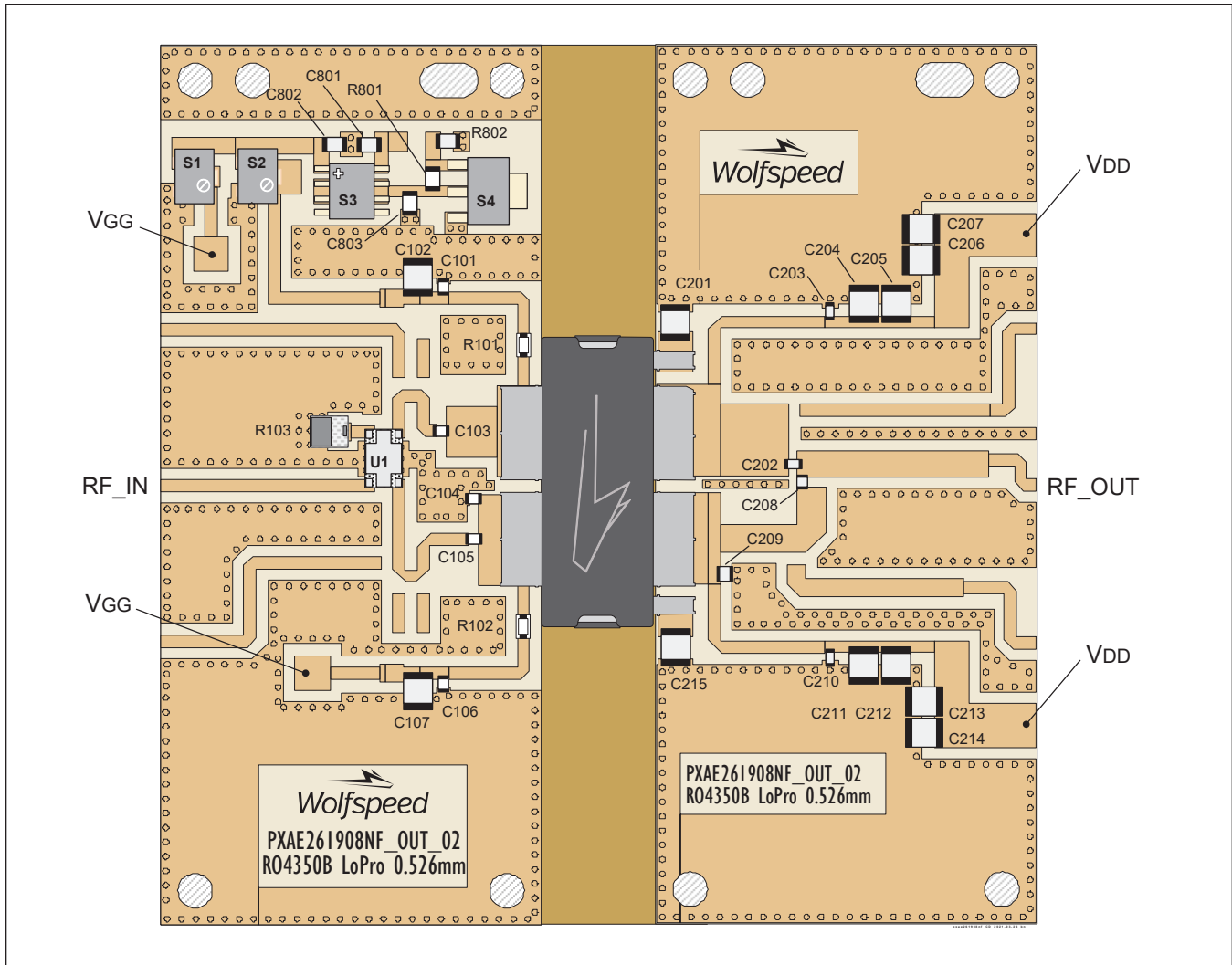
| | | P_{3dB} | | | | | | | | | | |
|-------------------|--------------------------|--------------------------|------------------|------------------------------|----------------------------|--------------------------|-----------------------------|------------------|------------------------------|----------------------------|--------------------------|--|
| | | Max Output Power | | | | | Max Drain Efficiency | | | | | |
| Freq [MHz] | Z_s [Ω] | Z_l [Ω] | Gain [dB] | P_{3dB} [dBm] | P_{3dB} [W] | η_D [%] | Z_l [Ω] | Gain [dB] | P_{3dB} [dBm] | P_{3dB} [W] | η_D [%] | |
| 2515 | 3.0 – j13.2 | 4.9 – j8.1 | 11.8 | 53.12 | 205 | 55.5 | 5.0 – j3.9 | 13.4 | 51.80 | 151 | 65.0 | |
| 2595 | 3.4 – j14.5 | 5.7 – j8.7 | 12.0 | 53.00 | 200 | 53.3 | 4.8 – j4.8 | 13.5 | 52.00 | 158 | 63.0 | |
| 2675 | 6.3 – j15.0 | 6.3 – j8.9 | 12.3 | 52.80 | 191 | 52.4 | 4.7 – j5.4 | 13.6 | 51.90 | 155 | 60.0 | |

See next page for evaluation circuit information.



Evaluation Circuit, 2515 – 2675 MHz

| | |
|-----------------------|--|
| DUT | PXAE261908NF V1 |
| Test Fixture Part No. | LTA/PXAE261908NF-V1 |
| PCB | Rogers 4350B LoPro , 0.526 mm [0.0207"] thick, 1 oz. copper, $\epsilon_r = 3.66$ |



Evaluation circuit assembly diagram (not to scale)

Bias Sequencing

Bias ON

1. Ensure RF is turned off
2. Apply pinch-off voltage of 0 V to the gate
3. Apply nominal drain voltage
4. Bias gate to desired quiescent drain current
5. Apply RF

Bias OFF

1. Turn RF off
2. Apply pinch-off voltage of 0 V to the gate
3. Turn off drain voltage
4. Turn off gate voltage

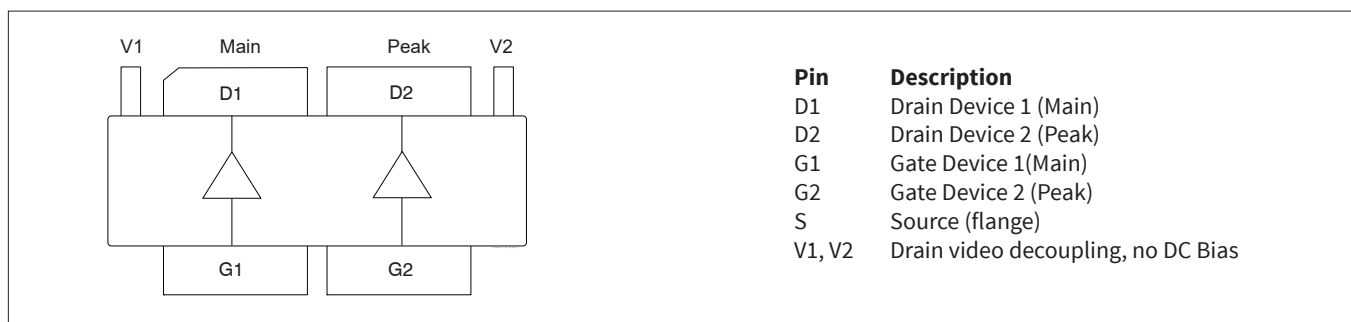


Evaluation Circuit (cont.)

Components Table

| Component | Description | Manufacturer | P/N |
|--|-----------------------------|---------------------------------|--------------------|
| Input | | | |
| C101, C103, C105, C106 | Capacitor, 20 pF | ATC | ATC800A200JT250T |
| C102, C107 | Capacitor, 10 μ F, 50 V | Taiyo Yuden | UMK325C7106MM-T |
| C104 | Capacitor, 0.6 pF | ATC | ATC800A0R6CT250T |
| R101, R102 | Resistor, 2.49 ohms | Vishay Dale | CRCW12062R49FKEA |
| R103 | Resistor, 50 ohms | RICHARDSON | C8A50Z4A |
| U1 | Hybrid coupler | ANAREN | X3C35P1-02S |
| C801, C802, C803 | Capacitor, 1,000 pF | Murata Electronics | GRM188R72A102KA01D |
| R801 | Chip resistor, 1.2K ohms | Panasonic Electronic Components | ERJ-3GEYJ122V |
| R802 | Chip resistor, 1.3K ohms | Panasonic Electronic Components | ERJ-3GEYJ132V |
| S1, S2 | Variable resistor, 2K ohms | Bourns Inc. | 3224W-1-202E |
| S3 | Voltage regulator | Texas Instruments | LM78L05ACM |
| S4 | Transistor | Diodes Incorporated | BCP5616TA |
| Output | | | |
| C201, C204, C205, C206, C207, C211, C212, C213, C214, C215 | Capacitor, 10 μ F, 50 V | Taiyo Yuden | UMK325C7106MM-T |
| C202 | Capacitor, 3.9 pF | ATC | ATC800A3R9CT250T |
| C203, C208, C210 | Capacitor, 20 pF | ATC | ATC800A200JT250T |
| C209 | Capacitor, 1.0 pF | ATC | ATC100B1R0CW500XB |

Pinout Diagram (top view)



Package Outline Specifications

